

[Product Information]

Ver.1.0

IMX485LQJ

Diagonal 12.86 mm (Type 1/1.2) CMOS Solid-state Image Sensor with Square Pixel for Color Cameras

Description

The IMX485LQJ is a diagonal 12.8 mm (Type 1/1.2) CMOS active pixel type solid-state image sensor with a square pixel array and 8.42 M effective pixels. This chip operates with analog 2.9 V, digital 1.2 V, and interface 1.8 V triple power supply, and has low power consumption. High sensitivity, low dark current and no smear are achieved through the adoption of R, G and B primary color mosaic filters. This chip features an electronic shutter with variable charge-integration time.

(Applications: Surveillance cameras, FA cameras, Industrial cameras)

Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Input frequency: 6 to 27 MHz / 37.125 MHz / 74.25 MHz
- ◆ Number of recommended recording pixels: 3840 (H) × 2160 (V) approx. 8.29 M pixels
- ◆ Readout mode
 - All-pixel scan mode
 - Horizontal / Vertical 2/2-line binning mode
 - Window cropping mode
 - Horizontal / Vertical direction - Normal / Inverted readout mode
- ◆ Readout rate
 - Maximum frame rate in
 - All-pixel scan mode: 12 bit: 60 frame/s, 10 bit: 90 frame/s
- ◆ High dynamic range (HDR) function
 - Multiple exposure HDR
 - Digital overlap HDR
- ◆ Synchronizing sensors function
- ◆ Variable-speed shutter function (resolution 2H units)
- ◆ 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
 - 0 dB to 72 dB (step pitch 0.3 dB)
- ◆ Supports I/O
 - CSI-2 serial data output (2 Lane / 4 Lane / 8 Lane / 4 Lane × 2 ch) RAW10 / RAW12 output
- ◆ Recommended exit pupil distance: -30 mm to -∞

STARVIS

* STARVIS is a trademark of Sony Corporation. The STARVIS is back-illuminated pixel technology used in CMOS image sensors for surveillance camera applications. It features a sensitivity of 2000 mV or more per 1 μm^2 (color product, when imaging with a 706 cd/m² light source, F5.6 in 1 s accumulation equivalent), and realizes high picture quality in the visible-light and near infrared light regions.

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Device Structure

- ◆ CMOS image sensor
- ◆ Image size Diagonal 12.8 mm (Type 1/1.2) approx. 8.40 M pixels, All pixels
- ◆ Total number of pixels 3864 (H) × 2200 (V) approx. 8.50 M pixels
- ◆ Number of effective pixels 3864 (H) × 2180 (V) approx. 8.42 M pixels
- ◆ Number of active pixels 3864 (H) × 2176 (V) approx. 8.40 M pixels
- ◆ Number of recommended recording pixels 3840 (H) × 2160 (V) approx. 8.29 M pixels
- ◆ Unit cell size 2.9 μm (H) × 2.9 μm (V)
- ◆ Optical black
Horizontal (H) direction: Front 0 pixel, rear 0 pixel
Vertical (V) direction: Front 20 pixels, rear 0 pixel
- ◆ Dummy
Horizontal (H) direction: Front 0 pixel, rear 0 pixel
Vertical (V) direction: Front 0 pixel, rear 0 pixel
- ◆ Package 122 pin LGA

Image Sensor Characteristics

(Tj = 60 °C)

Item		Value	Remarks
Sensitivity (F5.6)	Typ.	9530 Digit	1/30 s accumulation 12 bit converted value
Saturation signal	Min.	3895 Digit	12 bit converted value

Basic Drive Mode

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All pixel	3840 (H) × 2160 (V) approx. 8.29 M pixels	90	CSI-2	10
Horizontal/ Vertical 2/2-line binning	1920 (H) × 1080 (V) approx. 2.07 M pixels	90	CSI-2	10